

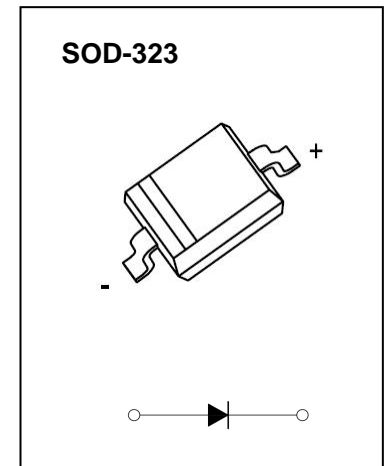
## High Voltage Switching Diode

**1. FEATURES**

- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- AEC-Q101 qualified (Automotive grade with suffix "Q!")
- Exsemi technology

**2. DEVICE MARKING AND RESISTOR VALUES**

Device	Marking	Shipping
BAS316	A6	3000/Tape&Reel

**3. MAXIMUM RATINGS(Ta = 25°C)**

Parameter	Symbol	Limits	Unit
Continuous Reverse Voltage	VR	100	V
Peak Forward Current	IF	250	mA
Peak Forward Surge Current	IFSM	500	mA

**4. THERMAL CHARACTERISTICS**

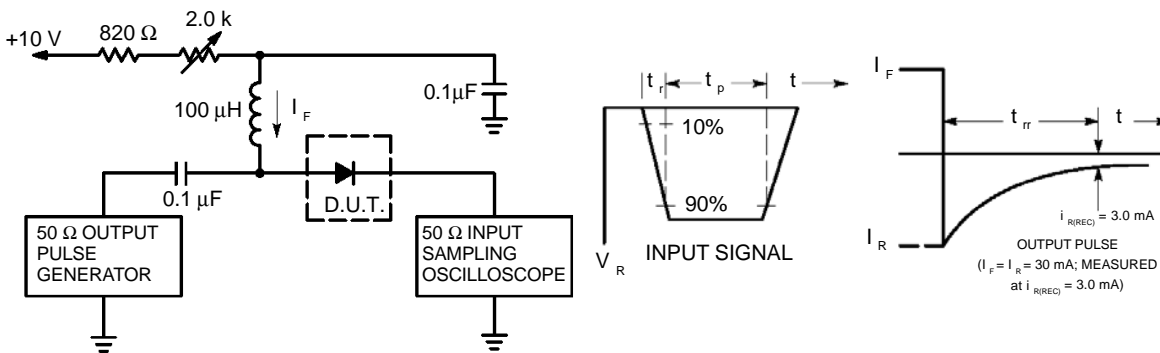
Parameter	Symbol	Limits	Unit
Total Device Dissipation FR-5 Board, (Note 1) TA = 25°C	PD	250	mW
Thermal Resistance, Junction to Ambient	RθJA	300	°C/W
Total Device Dissipation Alumina Substrate, (Note 2) TA = 25°C	PD	300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance, Junction to Ambient	RθJA	417	°C/W
Junction and Storage Temperature	TJ , Tstg	-55~+150	°C

1. FR-5 = 1.0 x 0.75 x 0.062 in.

2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

Characteristic	Symbol	Min	Max	Unit
Reverse Voltage Leakage Current ( $V_R = 75V_{dc}$ )	$I_R$	—	1.0	$\mu A_{dc}$
( $V_R = 75 V_{dc}, T_J = 150^\circ C$ )		—	50	
( $V_R = 25 V_{dc}, T_J = 150^\circ C$ )		—	30	
Reverse Breakdown Voltage ( $I_{BR} = 100 \mu A_{dc}$ )	$V_{(BR)}$	75	—	Vdc
Forward Voltage ( $I_F = 1.0 mAdc$ )	$V_F$	—	715	mV
( $I_F = 10 mAdc$ )		—	855	
( $I_F = 50 mAdc$ )		—	1000	
( $I_F = 150 mAdc$ )		—	1250	
Diode Capacitance ( $V_R = 0, f = 1.0 MHz$ )	$C_D$	—	2.0	pF
Forward Recovery Voltage ( $I_F = 10 mAdc, t_r = 20ns$ )	$V_{FR}$	—	1.75	Vdc
Reverse Recovery Time ( $I_F = I_R = 10 mAdc, R_L = 50 \Omega$ )	$t_{rr}$	—	6.0	ns
Stored Charge ( $I_F = 10 mAdc$ to $V_R = 5.0V_{dc}, R_L = 500 \Omega$ )	$Q_S$	—	45	pC

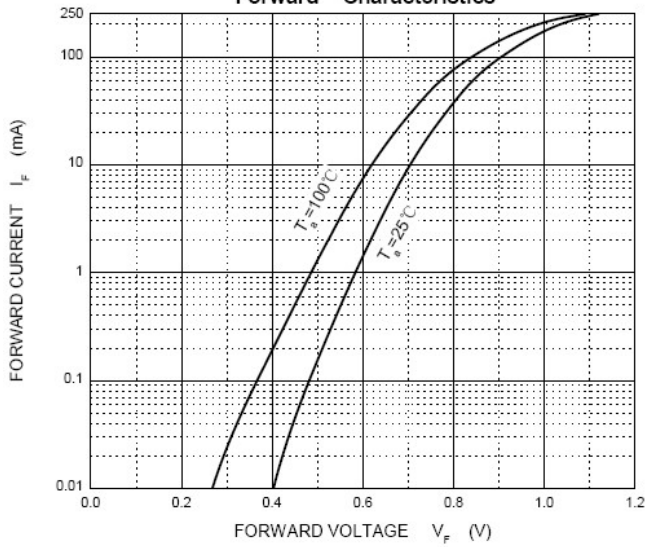


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.
- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 30 mA.
- 3.  $t_p \gg t_{rr}$

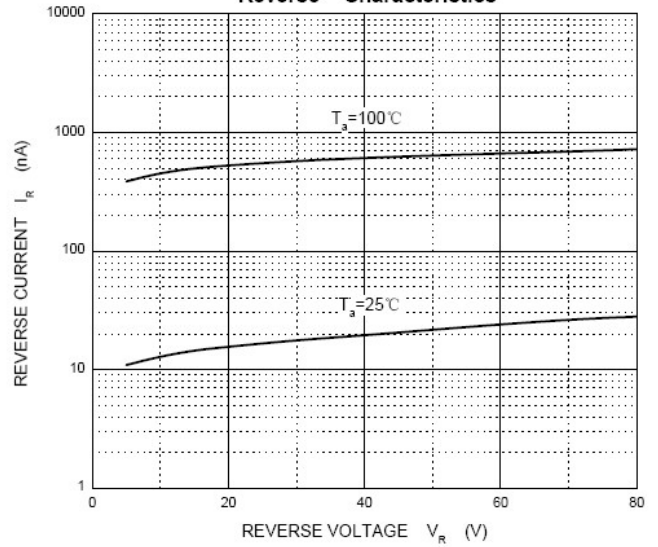
Figure 1. Recovery Time Equivalent Test Circuit

6.ELECTRICAL CHARACTERISTICS CURVES

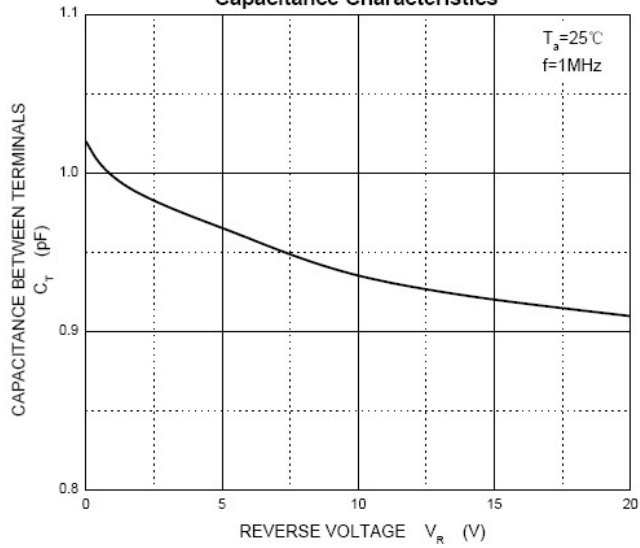
Forward Characteristics



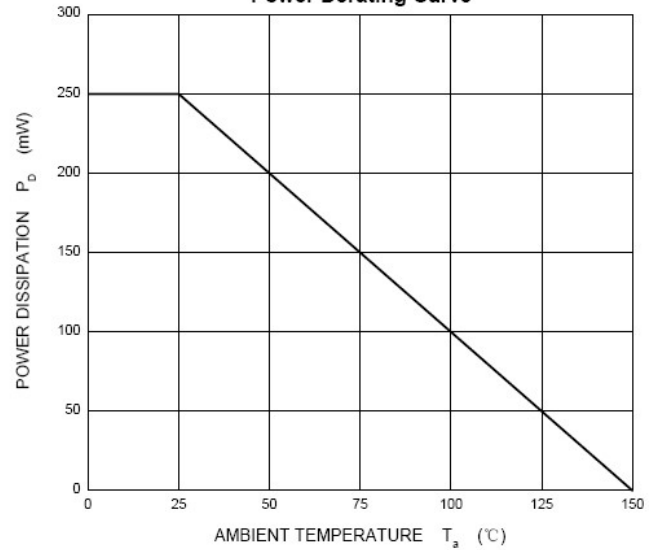
Reverse Characteristics



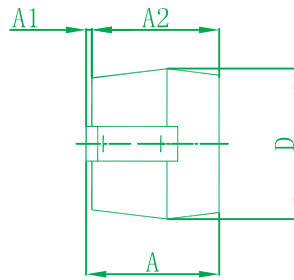
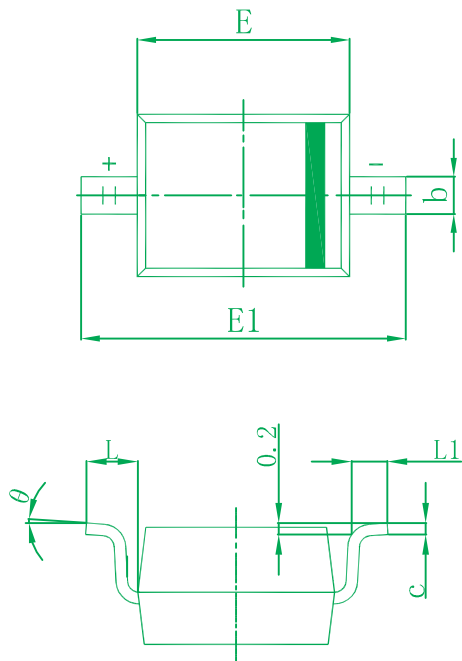
Capacitance Characteristics



Power Derating Curve

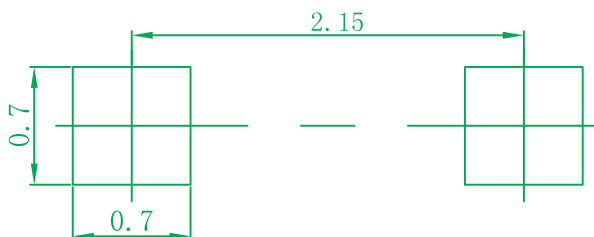


## 7.OUTLINE AND DIMENSIONS



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.150	0.035	0.045
b	0.250	0.400	0.010	0.015
c	0.080	0.150	0.003	0.006
D	1.150	1.400	0.045	0.055
E	1.600	1.800	0.063	0.071
E1	2.400	2.800	0.094	0.110
L	0.475 REF		0.019REF	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

## 8.SOLDERING FOOTPRINT

**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.